# The RF Line Microwave Pulse Power Transistors

Designed for Class B and C common base amplifier applications in short and long pulse TACAN, IFF, DME, and radar transmitters.

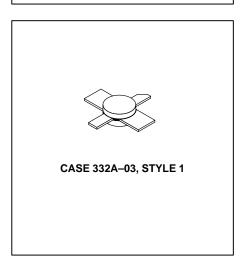
- Guaranteed Performance @ 1090 MHz, 50 Vdc Output Power = 35 Watts Peak Minimum Gain = 10 dB
- 100% Tested for Load Mismatch at All Phase Angles with 10:1 VSWR
- Industry Standard Package
- Nitride Passivated
- Gold Metallized, Emitter Ballasted for Long Life and Resistance to Metal Migration
- Internal Input Matching for Broadband Operation

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CES</sub>	60	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	60	Vdc
Emitter-Base Voltage	VEBO	4.0	Vdc
Collector-Current — Continuous	IC	2.0	Adc
Total Device Dissipation @ T <sub>C</sub> = 25°C (1) Derate above 25°C	PD	35 200	Watts mW/°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

## **MRF1035MB**

35 W (PEAK), 960-1215 MHz MICROWAVE POWER TRANSISTORS NPN SILICON



#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case (2)	$R_{ heta JC}$	5.0	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 20 mAdc, V <sub>BE</sub> = 0)	V(BR)CES	60	_	_	Vdc
Collector-Base Breakdown Voltage (IC = 20 mAdc, IE = 0)	V(BR)CBO	60	_	_	Vdc
Emitter-Base Breakdown Voltage (I <sub>E</sub> = 2.0 mAdc, I <sub>C</sub> = 0)	V(BR)EBO	4.0	_	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0)	ICBO	_	_	2.0	mAdc
ON CHARACTERISTICS					
DC Current Gain (I <sub>C</sub> = 500 mAdc, V <sub>CE</sub> = 5.0 Vdc)	hFE	10	40	100	_

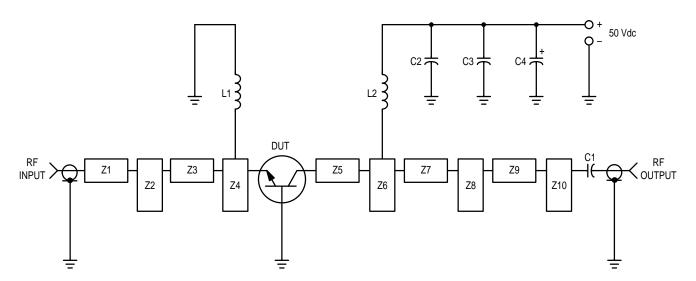
<sup>1.</sup> These devices are designed for RF operation. The total device dissipation rating applies only when the device is operated as RF amplifiers.



<sup>2.</sup> Thermal Resistance is determined under specified RF operating conditions by infrared measurement techniques.

### **ELECTRICAL CHARACTERISTICS** — **continued** ( $T_C = 25$ °C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
DYNAMIC CHARACTERISTICS					•
Output Capacitance (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>ob</sub>	_	10	15	pF
FUNCTIONAL TESTS (Pulse Width = 10 μs, Duty Cycle = 1%)					
Common-Base Amplifier Power Gain (V <sub>CC</sub> = 50 Vdc, P <sub>out</sub> = 35 W Peak, f = 1090 MHz)	GPB	10	12.4	_	dB
Collector Efficiency (V <sub>CC</sub> = 50 Vdc, P <sub>out</sub> = 35 W Peak, f = 1090 MHz)	η	30	34	_	%
Load Mismatch (V <sub>CC</sub> = 50 Vdc, P <sub>Out</sub> = 35 W Peak, f = 1090 MHz, VSWR = 10:1 All Phase Angles)	Ψ	No Degradation in Power Output			



C1, C2 — 220 pF 100 mil Chip Capacitor C3 — 0.1  $\mu$ F C4 — 10  $\mu$ F/75 V Electrolytic L1, L2 — 3 Turns #18 AWG, 1/8" ID Z1–Z10 — Microstrip, See Photomaster Board Material — 0.031" Glass Teflon  $\epsilon_\Gamma$  = 2.5

Figure 1. 1090 MHz Test Circuit

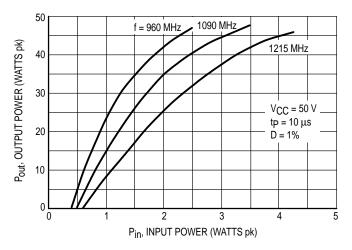


Figure 2. Output Power versus Input Power

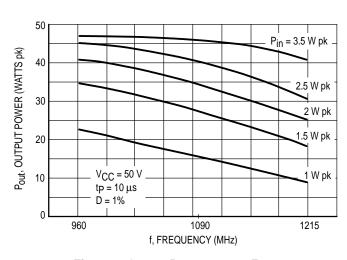


Figure 3. Output Power versus Frequency

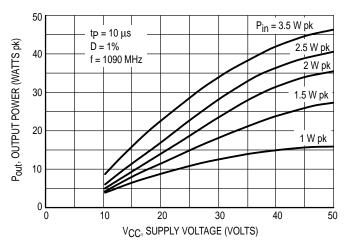


Figure 4. Output Power versus Supply Voltage

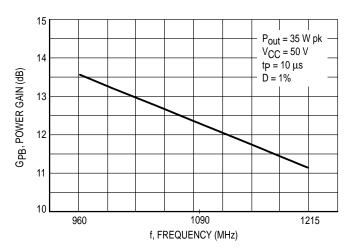
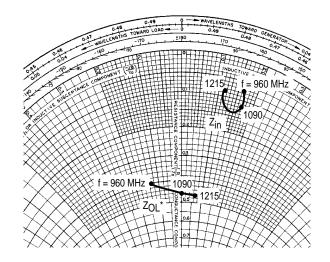


Figure 5. Power Gain versus Frequency



 $P_{out} = 35 \text{ W pk} \quad V_{CC} = 50 \text{ V}$  $t_p = 10 \,\mu s$  D = 1%

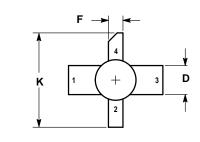
f	Z <sub>in</sub>	Z <sub>OL</sub> *
MHz	Ohms	Ohms
960	3.8 + j8.2	7.5 – j3.3
1090	6.0 + j8.2	9.0 + j0
1215	4.2 + j5.7	9.1 + j1.7

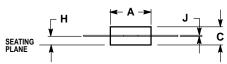
 $Z_{OL}^*$  = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage, and frequency.

Figure 6. Series Equivalent Input/Output Impedances

MOTOROLA RF DEVICE DATA MRF1035MB

#### PACKAGE DIMENSIONS





- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.270	0.290	6.86	7.36
C	0.115	0.135	2.93	3.42
D	0.195	0.205	4.96	5.20
F	0.095	0.105	2.42	2.66
Н	0.050	0.070	1.27	1.77
J	0.003	0.007	0.08	0.17
K	0.600		15.24	

STYLE 1:

PIN 1. BASE 2. EMITTER

- 3. BASE 4. COLLECTOR

**CASE 332A-03 ISSUE D** 

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